One Watt High Current Transistors

Symbol

V_{CEO}

V_{CBO}

VEBO

 I_{C}

 P_D

 P_D

T_J, T_{stg}

Symbol

 $R_{\theta JA}$

 $R_{\theta JC}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the

Recommended Operating Conditions may affect device reliability.

MPSW01

MPSW01A

MPSW01

MPSW01A

Value

30

40

40

50

5.0

1000

1.0

8.0

2.5

20

-55 to +150

Max

125

50

Unit

Vdc

Vdc

Vdc

mAdc

w

mW/°C

W

mW/°C

°C

Unit

°C/W

°C/W

NPN Silicon

MAXIMUM RATINGS

Collector - Emitter Voltage

Collector-Base Voltage

Emitter - Base Voltage

Derate above 25°C

Derate above 25°C

Temperature Range

Collector Current - Continuous

Total Device Dissipation @ T_A = 25°C

Total Device Dissipation @ T_C = 25°C

Operating and Storage Junction

THERMAL CHARACTERISTICS Characteristic

Thermal Resistance, Junction-to-Ambient

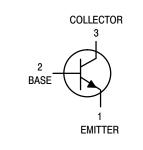
Thermal Resistance, Junction-to-Case

Features

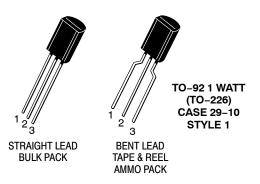
Pb–Free Packages are Available*

Rating

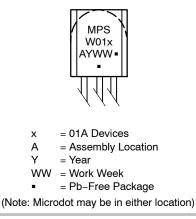




http://onsemi.com



MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MPSW01, MPSW01A

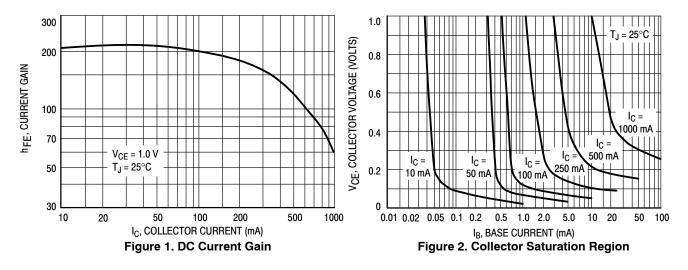
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 1) (I _C = 10 mAdc, I _B = 0)	MPSW01 MPSW01A	V _(BR) CEO	30 40		Vdc
Collector – Base Breakdown Voltage (I _C = 100 μ Adc, I _E = 0)	MPSW01 MPSW01A	V _{(BR)CBO}	40 50		Vdc
Emitter – Base Breakdown Voltage ($I_E = 100 \ \mu Adc$, $I_C = 0$)		V _{(BR)EBO}	5.0	-	Vdc
Collector Cutoff Current $(V_{CB} = 30 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 40 \text{ Vdc}, I_E = 0)$	MPSW01 MPSW01A	I _{CBO}		0.1 0.1	μAdc
Emitter Cutoff Current ($V_{EB} = 3.0 \text{ Vdc}, I_C = 0$)		I _{EBO}	-	0.1	μAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain (I _C = 10 mAdc, V _{CE} = 1.0 Vdc) (I _C = 100 mAdc, V _{CE} = 1.0 Vdc) (I _C = 1000 mAdc, V _{CE} = 1.0 Vdc)		h _{FE}	55 60 50		-
Collector – Emitter Saturation Voltage (I_C = 1000 mAdc, I_B = 100 mAdc)		V _{CE(sat)}	-	0.5	Vdc
Base-Emitter On Voltage (I _C = 1000 mAdc, V _{CE} = 1.0 Vdc)		V _{BE(on)}	-	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain — Bandwidth Product (I_C = 50 mAdc, V_{CE} = 10 Vdc, f =	20 MHz)	f _T	50	-	MHz
Output Capacitance (V_{CB} = 10 Vdc, I_E = 0, f = 1.0 MHz)		C _{obo}	_	20	pF
. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.			-		•

ORDERING INFORMATION

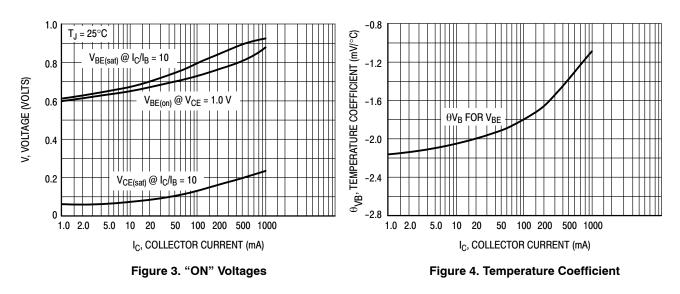
Device	Package	Shipping [†]	
MPSW01	TO-92	5000 Units / Bulk	
MPSW01G	TO-92 (Pb-Free)	5000 Units / Bulk	
MPSW01AG	TO-92 (Pb-Free)	5000 Units / Bulk	
MPSW01ARLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel	
MPSW01ARLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



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MPSW01, MPSW01A



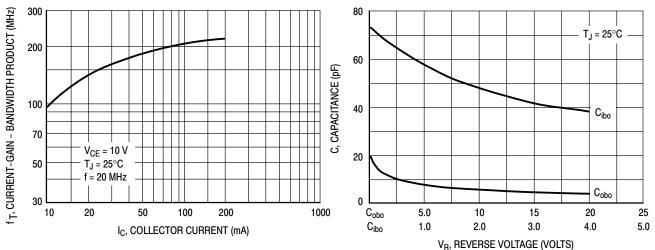


Figure 5. Current Gain — Bandwidth Product

Figure 6. Capacitance

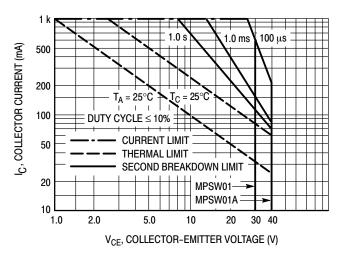
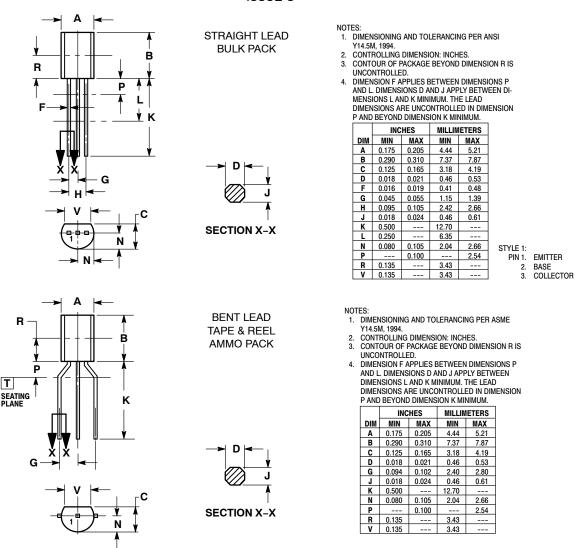


Figure 7. Active Region — Safe Operating Area

PACKAGE DIMENSIONS

TO-92 (TO-226) 1 WATT CASE 29-10 ISSUE O



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